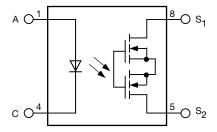


1500 V, 1 Form A Solid-State Relay





DESCRIPTION

The VORA1150 is an AEC-Q102 qualified 1500 V solid-state relay in an innovative 4-pin SMD-8 package with > 5 mm creepage distance in between the output pins making it suitable for use in 800 V automotive applications. It consists of an infrared emitter that is optically coupled to high voltage MOSFETs between the output terminals.

This device provides reinforced isolation and is suitable for use in automotive and industrial applications.

FEATURES

- AEC-Q102 qualified
- Isolation test voltage 5300 V_{RMS}
- Typical R_{ON} 100 Ω
- Load voltage 1500 V
- Load current 50 mA
- Ambient temperature range -40 °C to +125 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





RoHS

COMPLIANT HALOGEN FREE **GREEN** <u>(5-2008)</u>

APPLICATIONS

- Battery isolation measurement in electric vehicles
- · Pre-charge relay
- · On-board charger
- · Battery management system
- Solar panel leakage current detection

AGENCY APPROVALS

- UL (pending)
- cUL (pending)
- DIN EN 60747-5-5 (VDE0884-5) (pending)

ORDERING INFORMATION		
V O R A 1 1 5 0 - PART NUMBER	X 0 1 7 T ORDERING INFORMATION > 0.1 mm	
PACKAGE	UL, VDE	
SMD-8, tape and reel	VORA1150-X017T	



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	CONDITION	SYMBOL	VALUE	UNIT				
INPUT	INPUT							
IRED continuous forward current		I _F	50	mA				
IRED reverse voltage		V_{R}	5	V				
Input power dissipation		P _{diss}	80	mW				
Junction temperature		T_J	140	°C				
OUTPUT								
Load voltage		V_{L}	1500	V				
Continuous load current		IL	50	mA				
SSR output power dissipation (continuous)		P _{diss}	550	mW				
Junction temperature		T_J	140	°C				
SSR								
Ambient temperature range		T _{amb}	-40 to +125	°C				
Storage temperature range		T _{stg}	-40 to +150	°C				
Soldering temperature	t = 10 s max.	T _{sld}	260	°C				
Repetitive avalanche rating	$t_p = 5 \text{ s, duty cycle} < 8.3 \% (1)$	I _{AVA}	0.9	mA				
High pot pulse width	$R_L = 940 \text{ k}\Omega, V_L = 2400 \text{ V}, 5 \text{ times over}$ lifetime, recovery time 60 s	t _{P_HiPot}	5	s				

Notes

⁽¹⁾ Cumulative of 5 min over lifetime with 60 s period.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	$I_F = 5 \text{ mA}$	V_{F}	-	1.35	1.6	٧
Reverse current	V _R = 5 V	I_R	-	-	10	μΑ
IRED forward current, switch turn - on	I _L = 50 mA	I _{Fon}	-	-	2	mA
IRED forward current, switch turn - off	$V_L = 1500 \text{ V}, I_L = 50 \mu\text{A}$	I _{Foff}	150	200	-	nA
OUTPUT						
On-resistance	$I_F = 5 \text{ mA}, I_L = 50 \text{ mA}$	R _{ON}	-	100	200	Ω
Off-state leakage current	$I_F = 0 \text{ mA}, V_L = \pm 1500 \text{ V}$	Io	-	< 1	1	μΑ
	$I_F = 0 \text{ mA}, V_L = \pm 1500 \text{ V}, T_{amb} = 85 \text{ °C}$	Io	-	0.05	-	μΑ
	$I_F = 0 \text{ mA}, V_L = \pm 1200 \text{ V}, T_{amb} = 100 \text{ °C}$	Io	-	0.15	-	μA
	$I_F = 0 \text{ mA}, V_L = \pm 1000 \text{ V}, T_{amb} = 110 ^{\circ}\text{C}$	Io	-	0.5	-	μA
Output capacitance	$I_F = 0 \text{ mA}, V_L = 25 \text{ V}, f = 1 \text{ MHz}$	Co	-	10	-	pF
TRANSFER						
Capacitance (input to output)	V _{IO} = 1 V, f = 1 MHz	C _{IO}	-	0.4	_	pF

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluations. Typical values are for information only and are not part of the testing requirements.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

PIN CONFIGURATION

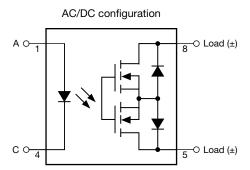


Fig. 1 - Pin Configuration

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn-on time	$I_F = 10 \text{ mA}, R_L = 20 \text{ k}\Omega, V_{DD} = 40 \text{ V}$	t _{on}	ı	50	150	μs
Turn-off time	$I_F = 10 \text{ mA}, R_L = 20 \text{ k}\Omega, V_{DD} = 40 \text{ V}$	t _{off}	-	80	250	μs

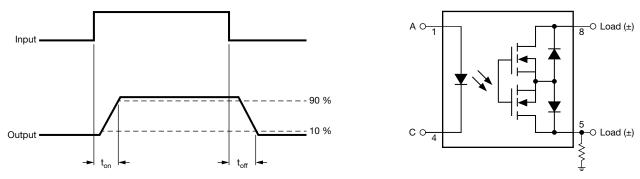


Fig. 2 - Timing Schematic



SAFETY AND INSULATION RATINGS					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Climatic classification	According to IEC 68 part 1		40 / 125 / 21		
Pollution degree	According to DIN VDE 0109		2		
Comparative tracking index	Insulation group IIIa	CTI	600		
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V _{ISO}	5300	V_{RMS}	
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V_{IOTM}	8000	V _{peak}	
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V _{IORM}	1414	V _{peak}	
	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω	
Isolation resistance	V _{IO} = 500 V, T _{amb} = 125 °C	R _{IO}	≥ 10 ¹¹	Ω	
	V _{IO} = 2000 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω	
	V _{IO} = 2000 V, T _{amb} = 125 °C	R _{IO}	≥ 10 ¹¹	Ω	
Output safety power		P _{SO}	1000	mW	
Input safety current		I _{SI}	240	mA	
Safety temperature		Ts	175	°C	
Creepage distance	SMD-8		≥ 8	mm	
Clearance distance	SMD-8		≥ 8	mm	
Insulation thickness		DTI	≥ 0.4	mm	
Input to output test voltage, method B	$V_{IORM} \times 1.875 = V_{PR}$, 100 % production test with $t_M = 1$ s, partial discharge < 5 pC	V_{PR}	2651	V _{peak}	
Input to output test voltage, method A	$V_{IORM} \times 1.6 = V_{PR}$, sample test with $t_M = 10$ s, partial discharge < 5 pC	V _{PR}	2262	V _{peak}	

Note

• As per IEC 60747-5-5, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

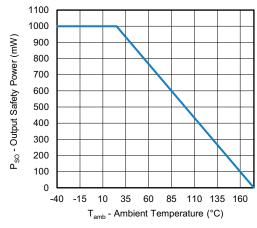


Fig. 3 - Safety Power Dissipation vs. Ambient Temperature

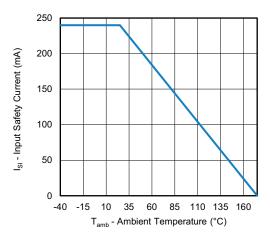
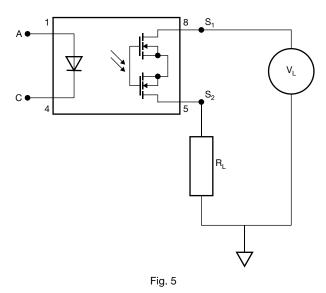


Fig. 4 - Safety Input Current vs. Ambient Temperature

HIPOT TESTING AND AVALANCHE BREAKDOWN

For the calculation of avalanche current flowing through the MOSFET of the solid-state relay and the respective power dissipated in the solid state relay below circuit is referred:



For the below mentioned conditions, the current through the MOSFETs is calculated as:

Load resistance $R_I = 940 \text{ k}\Omega \pm 5 \%$

$$V_L = 2400 V$$

MOSFETs breakdown voltage V_{BREAK} = 1500 V (min.)

$$I_{AVA} = \frac{V_R}{R_L} = \frac{V_L - V_{BREAK}}{R_L} = \frac{2400 \ V - 1500 \ V}{893 \ k\Omega} = 1 \ mA$$

From the current the power dissipated in the solid-state relay can be calculated as:

$$P_{MOS} = V_{BREAK} \times I_{AVA} = 1500 \text{ V} \times 1 \text{ mA} = 1.5 \text{ W}$$

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

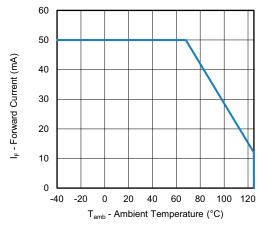


Fig. 6 - Forward Current vs. Ambient Temperature

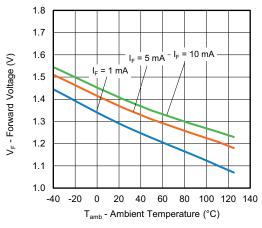


Fig. 7 - Forward Voltage vs. Ambient Temperature



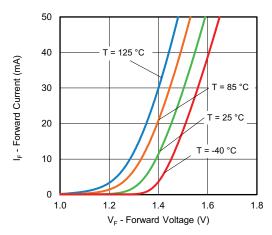


Fig. 8 - Forward Current vs. Forward Voltage

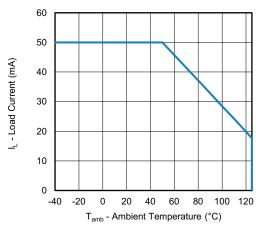


Fig. 9 - Maximum Load Current vs. Ambient Temperature

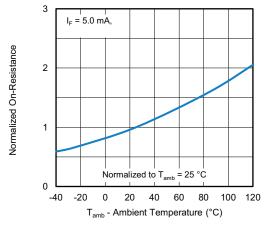


Fig. 10 - Normalized On-Resistance vs. Ambient Temperature

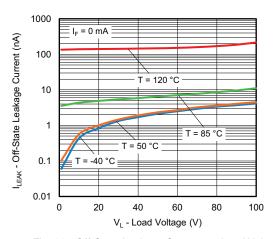


Fig. 11 - Off-State Leakage Current vs. Load Voltage

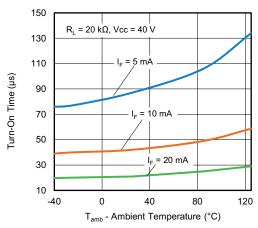


Fig. 12 - Turn-On Time vs. Ambient Temperature

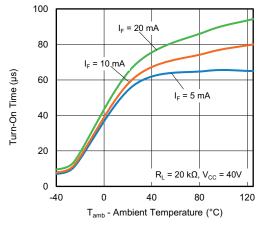


Fig. 13 - Turn-Off Time vs. Ambient Temperature

1.52

8.00 min. 11.05

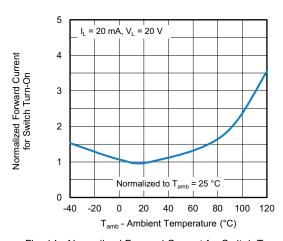


Fig. 14 - Normalized Forward Current for Switch Turn-On vs. Ambient Temperature

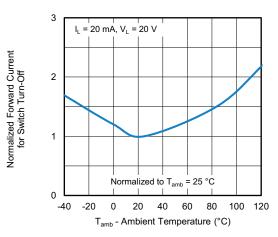


Fig. 15 - Normalized Forward Current for Switch Turn-Off vs.
Ambient Temperatur

PACKAGE DIMENSIONS (in millimeters)

SMD-8

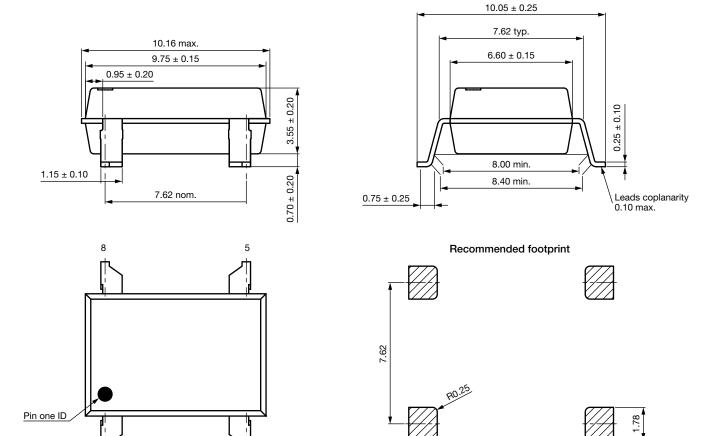


Fig. 16 - Package Drawings

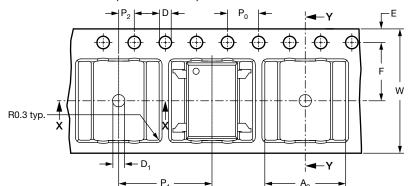


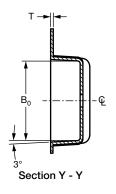
PACKAGE MARKING

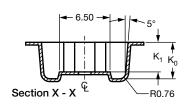


Fig. 17 - VORA1150

PACKING INFORMATION (in millimeters)







Symbol	Millimeters	Inches
A_0	10.41 ± 0.1	0.410 ± 0.004
B ₀	10.21 ± 0.1	0.402 ± 0.004
D	1.50 ^{+0.1}	0.059 ^{+0.004} -0.0
D ₁	1.50 ^{+0.25}	0.059 +0.010
E	1.75 ± 0.1	0.069 ± 0.004
F	7.50 ± 0.1	0.295 ± 0.004
K ₀	4.70 ± 0.1	0.185 ± 0.004
K ₁	3.81 ± 0.1	0.150 ± 0.004
P ₁	12.00 ± 0.1	0.472 ± 0.004
P_0	4.00 ± 0.1	0.157 ± 0.004
P_2	2.00 ± 0.1	0.079 ± 0.004
Т	0.35 ± 0.05	0.014 ± 0.002
W	16.00 ± 0.3	0.630 ± 0.012

Notes

- 10 sprocket hole pitch cummulative tolerances ± 0.2
- Camber not to exeed 1 mm in 100 mm
- Material: black conductive polystyrene
- K₀ measured from a plane on the inside bottom of the pocket to the top surface of the carrier
- Resistivity = $10^4 \Omega/\text{sq.}$ to $10^9 \Omega/\text{sq.}$

Fig. 18 - Tape and Reel Packing (1000 pieces on reel)

SOLDER PROFILES

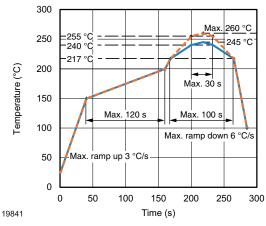


Fig. 19 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD Devices

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2

Floor life: 168 h

Conditions: T_{amb} < 30 °C, RH < 85 %

Moisture sensitivity level 3, according to J-STD-020



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